NSN 5961-01-029-1009

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Inclosure Material:

Metal

Overall Length:

0.190 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.219 inches

Internal Configuration:

Field effect

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 drain to gate voltage and 50.0 gate to source voltage

Current Rating Per Characteristic:

30.00 milliamperes zero-gate-voltage drain current and 0.10 amperes reverse gate current with all other terminals short-circuit to source, junction-gate

Power Rating Per Characteristic:

350.0 milliwatts total device dissipation

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Terminal Type And Quantity:

4 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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